8-UNIT 400mA DARLINGTON TRANSISTOR ARRAY

#### **DESCRIPTION**

M54583P and M54583FP are eight-circuit collector-currentsynchronized Darlington transistor arrays. The circuits are made of PNP and NPN transistors. Both the semiconductor integrated circuits perform high-current driving with extremely low input-current supply.

#### **FEATURES**

- High breakdown voltage (BVcEo ≥ 50V)
- High-current driving (Ic(max) = 400mA)
- Active L-level input
- With input clamping diodes
- Wide operating temperature range (Ta = -20 to +75°C)

#### **APPLICATION**

Interfaces between microcomputers and high-voltage, high-current drive systems, drives of relays and printers, and MOS-bipolar logic IC interfaces

#### **FUNCTION**

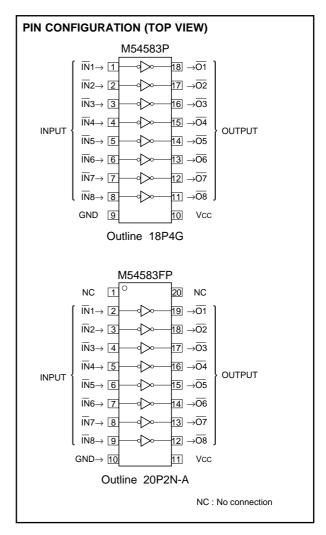
The M54583 is produced by adding PNP transistors to M54523 inputs. Eight circuits having active L-level inputs are provided.

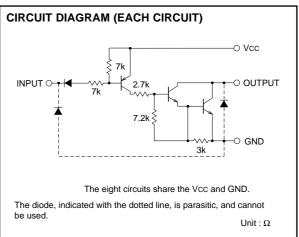
Resistance of  $7k\Omega$  and diode are provided in series between each input and PNP transistor base. The input diode is intended to prevent the flow of current from the input to the Vcc. Without this diode, the current flow from "H" input to the Vcc and the "L" input circuits is activated, in such case where one of the inputs of the 8 circuits is "H" and the others are "L" to save power consumption. The diode is inserted to prevent such misoperation.

This device is most suitable for a driver using NMOS IC output especially for the driver of current sink.

Collector current is 400mA maximum. Collector-emitter supply voltage is 50V.

The 54583FP is enclosed in a molded small flat package, enabling space saving design.







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# ABSOLUTE MAXIMUM RATINGS (Unless otherwise noted, Ta = $-20 \sim +75^{\circ}$ C)

Symbol	Parameter	Conditions	Ratings	Unit
Vcc	Supply voltage		10	V
VCEO	Collector-emitter voltage	Output, H	−0.5 ~ <b>+</b> 50	V
Vı	Input voltage		−0.5 ~ Vcc	V
Ic	Collector current	Current per circuit output, L	400	mA
Pd	Power dissipation	Ta = 25°C, when mounted on board	1.79/1.1	W
Topr	Operating temperature		<b>−20 ~ +75</b>	°C
Tstg	Storage temperature		<b>−</b> 55 ~ <b>+</b> 125	°C

#### RECOMMENDED OPERATING CONDITIONS (Unless otherwise noted, Ta = -20 ~ +75°C)

Cumbal	Parameter		Limits			l lmi4
Symbol			min	typ	max	Unit
Vcc	Supply voltage		4	5	8	V
	Collector current Per channel	Vcc = 5V, Duty Cycle P: no more than 10% FP: no more than 5%	0		350	mA
Ic		Vcc = 5V, Duty Cycle P: no more than 34% FP: no more than 15%	0	_	200	ША
VIH	"H" input voltage		Vcc-0.7	_	Vcc	V
VIL	"L" input voltage		0	1	Vcc-3.6	V

### ELECTRICAL CHARACTERISTICS (Unless otherwise noted, Ta = -20 ~ +75°C)

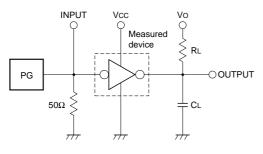
Symbol	Parameter	Tool	Limits			Llmit	
		Test conditions		min	typ*	max	Unit
V (BR) CEO	Collector-emitter breakdown voltage	ICEO = 100μA, VCC = 8V		50	_	_	V
VCE (sat)	Collector-emitter saturation voltage	VI = VCC-3.6V	Ic = 350mA	_	1.1	2.2	V
			Ic = 200mA	_	0.98	1.6	
lı	Input current	VI = VCC-3.6V		_	-320	-600	μΑ
Icc	Supply current (one circuit coming on)	VCC = 5V, VI = VCC-3.6V		_	_	3	mA
hFE	DC amplification factor	VCE = 4V, VCC = 5V, IC = 350mA, Ta = 25°C		2000	10000	_	_

<sup>\*:</sup> The typical values are those measured under ambient temperature (Ta) of 25°C. There is no guarantee that these values are obtained under any conditions.

### SWITCHING CHARACTERISTICS (Unless otherwise noted, Ta = 25°C)

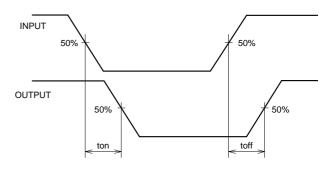
Symbol	Parameter	Test conditions	Limits			Unit
		rest conditions	min	typ	max	UIIII
ton	Turn-on time	CL = 15pF (note 1)	_	130	_	ns
toff	Turn-off time		_	3200	_	ns

#### **NOTE 1 TEST CIRCUIT**



- (1) Pulse generator (PG) characteristics : PRR = 1kHz, tw = 10 $\mu$ s, tr = 6ns, tf = 6ns, Zo = 50 $\Omega$  Vı = 0.4 to 4V
- (2) Input-output conditions : RL =  $30\Omega$ , Vo = 10V, Vcc = 4V
- (3) Electrostatic capacity CL includes floating capacitance at connections and input capacitance at probes

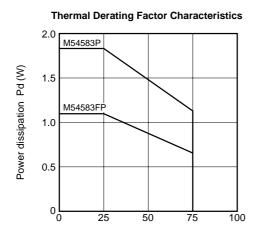
#### **TIMING DIAGRAM**



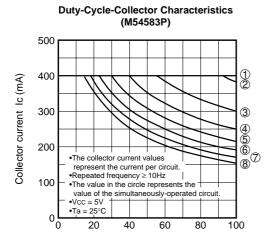


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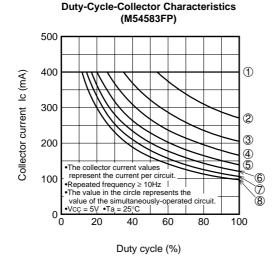
### TYPICAL CHARACTERISTICS



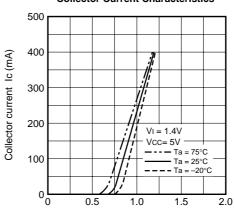
Ambient temperature Ta (°C)



Duty cycle (%)

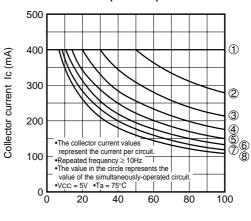


Output Saturation Voltage Collector Current Characteristics



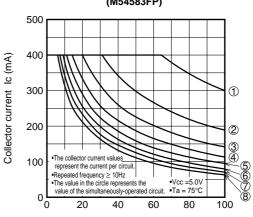
Output saturation voltage VCE (sat) (V)

Duty-Cycle-Collector Characteristics (M54583P)



Duty cycle (%)

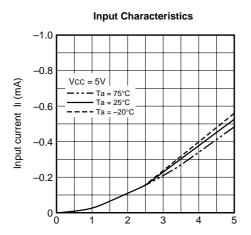
Duty-Cycle-Collector Characteristics (M54583FP)



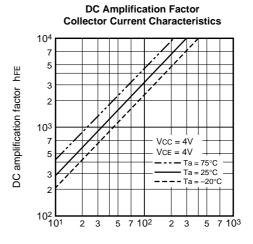
Duty cycle (%)



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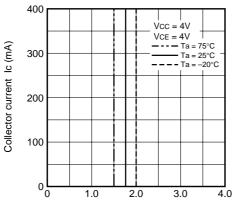


Supply voltage-Input voltage Vcc-Vi (V)



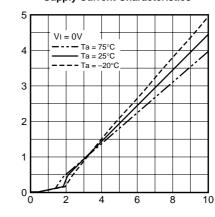
Collector current Ic (mA)





Supply voltage-Input voltage Vcc-Vi (V)

### **Supply Current Characteristics**



Supply current Icc (mA)

Supply voltage Vcc (V)

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